

# 3.020 Lecture 9

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# 1 Heat Capacity: Key to the (thermo) Kingdom

- $G = H - TS$
- equilibrium at fixed  $T$  &  $P$  is a balance between  $H$  and  $S$

Q: How to calculate  $H$  and  $S$  for a given phase at a given  $(T, P)$  ?

## 1.1 Calculating $H(T)$ at fixed $P$

$$\begin{aligned}H &= U + PV \\dH &= dU + PdV + VdP \quad \leftarrow \text{chain rule} \\&= TdS - PdV + PdV + VdP \quad \leftarrow \text{combined statement} \\&= TdS + VdP \\dH_P &= TdS = \delta Q_{rev} = C_P dT\end{aligned}$$

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$$H(T_2, P) = H(T_1, P) + \int_{T_1}^{T_2} dH = H(T_1, P) + \int_{T_1}^{T_2} dT C_P(T)$$

need  $C_P(T)$

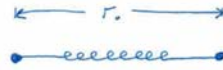
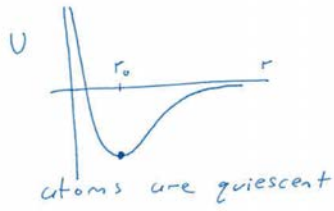
## 1.2 Calculating $S(T)$ at fixed $P$

$$\begin{aligned}dS &= \frac{C_P}{T} dT - V\alpha dP \quad \leftarrow \text{DeHoff table 4.5} \\dS_P &= \frac{C_P}{T} dT \\S(T_2, P) &= S(T_1, P) + \int_{T_1}^{T_2} dS = S(T_1, P) + \int_{T_1}^{T_2} dT \frac{C_P(T)}{T}\end{aligned}$$

need  $C_P(T)$

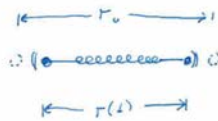
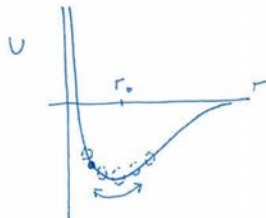
Q: What is  $C_P(T)$  for real materials ?

- Consider bonds as atoms on springs



low energy/  
low entropy

// vs. //



higher energy/  
higher entropy

- Models for  $C_P(T)$  that consider **vibrations of atoms in crystals** = phonons
  - Einstein: all vibrations have fixed frequency
  - Debye: range of vibration frequencies available  
(will solve these models later in the class, using stat. mech.)

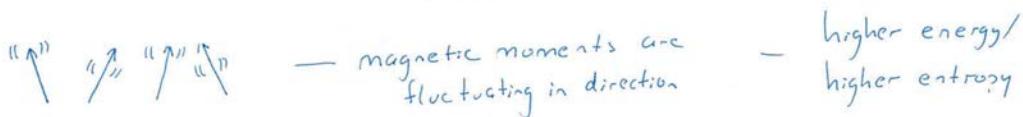
slides: 1. Einstein & Debye models; 2. Heat capacity of cobalt

- Heat capacity includes all “degrees of freedom” within a system  
e.g. molecular rotation, electronic states, magnetism, etc ...
- Consider ferromagnet such as cobalt

ways of partitioning energy



// vs. //



slide:  $C_P(T)$  of cobalt, again

## 2 Phase transformations

- Consider  $S \leftrightarrow L$  transformation in Si
- Enthalpy change  $\Delta H^{S \rightarrow L}(T_m) = 50.2 \text{ kJ/mol}$   
change at the equilibrium melting temp  $T_m = 1685 \text{ K} (1412^\circ \text{C})$

Q. What is enthalpy change  $\Delta H^{S \rightarrow L}$  for  $T < T_M$  ?

– For S phase:  $H^s(T) = H^s(T_M) + \int_{T_M}^T dT' C_P^s(T')$

– For L phase:  $H^L(T) = H^L(T_M) + \int_{T_M}^T dT' C_P^L(T')$

$$\Delta H^{S \rightarrow L}(T) = \Delta H^{S \rightarrow L}(T_M) + \int_{T_M}^T dT' (C_P^L - C_P^S)$$

$$(C_P^L - C_P^S) = \Delta C_P^{S \rightarrow L}(T) \quad \rightarrow \text{heat capacity difference}$$

slides: Si  
thermo data

- Use thermo data

– from NIST,  $C_P = A + Bt + Ct^2 + Dt^3 + E/t^2$ ,

empirical

$$t = \frac{T}{1000 \text{ K}}$$

	A (J/k.mol)	B (J/k.mol)	C	...
S	22.82	3.90	(-)	(-)
L	27.20	(-)	(-)	(-)

by inspection, choose to ignore these terms

$$\Delta C_P^{S \rightarrow L}(T) = (A^L - A^S) + \underbrace{(B^L - B^S)}_0 t + \dots$$

$$= (A^L - A^S) + (-B^S) \frac{T}{1000K}$$

$$\Delta H^{S \rightarrow L}(T) = \Delta H^{S \rightarrow L}(T_M) + (A^L - A^S)(T - T_M) - \left(\frac{B^S}{1000K}\right) \frac{1}{2}(T^2 - T_M^2)$$

Very important quantity for controlling Si solidification, critical process for making computer chips & solar cells

slide:  $\Delta H$   
plotted

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